



APT29F100B2 Information



For Reference Only

Part Number APT29F100B2

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1000V 30A T-MAX

Package TO-247-3 Variant

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APT29F100B2 Specifications

Manufacturer Part Number	APT29F100B2
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3 Variant
Series	POWER MOS 8?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	30A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 2.5mA
Gate Charge (Qg) (Max) @ Vgs	260nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	8500pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	1040W (Tc)
Rds On (Max) @ Id, Vgs	440 mOhm @ 16A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	T-MAX? [B2]
Package / Case	TO-247-3 Variant
	Report errors?

APT29F100B2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APT29F100B2 Payment Methods





















APT29F100B2 Shipping Methods













If you have any question about APT29F100B2, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com